Real space nite di erence method for conductance calculations

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W e present a general method for calculating coherent electronic transport in quantum wires and tunnel junctions. It is based upon a real space high order nite di erence representation of the single particle H am iltonian and wave functions. Landauer's form ula is used to express the conductance as a scattering problem. Dividing space into a scattering region and left and right ideal electrode regions, this problem is solved by wave function matching (W FM) in the boundary zones connecting these regions. The method is tested on a model tunnel junction and applied to sodium atom ic wires. In particular, we show that using a high order nite di erence approximation of the kinetic energy operator leads to a high accuracy at moderate com putational costs.

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I. IN TRODUCTION

The progress in experim ental controlon the nanom eter scale has enabled studies of electronic transport in quantum wires of atom ic dim ensions.¹ The transport properties of such systems have to be understood on the basis of their atom ic structure. This notion has generated a large e ort in recent years to calculate the conductance of quantum wires from st principles. Several di erent approaches have been form ulated, which have a comm on basis in the Landauer-Buttiker approach to express the conductance of a coherent system in terms of a quantum mechanical scattering problem .² In such calculations the quantum wire consists of a scattering region of nite size, sandwiched between two sem i-in nite leads that are considered to be ideal ballistic wires. Sem i-em pirical tight-binding models have been exploited to solve this problem .^{3,4,5,6} A in ing at a better description of the electronic structure, several current approaches rely upon density functional theory (DFT).

The main di erences between these approaches lie in the approxim ations that are used to describe the atom ic structure of the leads and in the techniques that are used to solve the scattering problem . In pioneering work, jellium (i.e. free electron) electrodes have been used to describe the leads and the scattering wave functions have been obtained by a transferm atrix method⁷ or by solving the Lippm an-Schwinger equation.^{8,9} A transferm atrix method has also been used taking into account the full atom ic structure of the leads at the DFT level.^{10,11} A Itematively, the conductance can be calculated using a G reen function approach without calculating the scattering wave functions explicitly.¹² Several im plementations of this approach have been formulated that use a localized basis set to form a representation of the scattering problem. These im plementations mainly dier in the kind of basis set used, e.g. Gaussian or num erical atom ic orbitals, or wavelets.^{13,14,15,16,17,18,19} An embedded Green function approach has been applied using a delocalized basis set of augmented plane waves.²⁰

In this paper we present a technique for solving the

scattering problem of a quantum wire without the use of a basis set. Instead, potentials and wave functions are represented on a uniform real space grid and di erential operators are approximated by a nite di erence approximation (FDA). Previous im plementations of this idea have used a simple rst order FDA.^{21,22,23,24} In that case the grid has to be relatively ne in order to obtain su ciently converged results. This hinders the application to large system s because of the computational costs involved in using ne grids. However, in ground state (DFT) electronic structure calculations high order FDA's have been shown to markedly increase the e ciency of real space grid techniques by enabling the use of coarse grids.^{25,26,27} In this paper we dem onstrate that high order FDA 's make it possible to solve the scattering problem much more e ciently.

The method we propose for calculating the conductance of a quantum wire is based upon wave function matching (WFM) in the boundary zones connecting the leads and the scattering region.²⁸ Unlike transferm atrix m ethods, how ever, it does not require the explicit calculation of wave functions in the scattering region.^{7,10,11} It does not require the explicit calculation of Green functions either,^{12,13,14,15,16,17,18,19,20} which enables us to solve the scattering problem at real, instead of com plex, energies.²⁹ Ourm ethod can be classied as an O (N) technique, since the computing costs are determined by the size of the scattering region with which they scale linearly. A related technique that uses a linearized mun tin orbital basis set, has been applied to calculate the electronic transport in layered magnetic materials.^{30,31} A lthough the form alism presented here can be extended to the non-equilibrium situation, we consider in this paper the linear response regime only.

This paper is organized as follows. In Sec. II the main ingredients of our computational method are explained, where the computational details can be found in appendix A. The accuracy and convergence properties of the method are veried on model tunnel junctions in Sec. IIIA. The application to a more complex system, which consists of a sodium atom ic wire, is discussed in

Sec. IIIB. A summary is given in Sec. IV.

II. COMPUTATIONALMETHOD

W ithin the Landauer-Buttiker approach the conductance G of a quantum wire is expressed in terms of the total transm ission T $({\rm E}$)

$$G = \frac{e^2}{2} T (E); \qquad (1)$$

assuming spin degeneracy.² T(E) can be obtained by solving the quantum mechanical scattering problem at the xed energy E. Eq. (1) is valid in the linear response regime, where T (E) needs to be evaluated at the Ferm i energy $E = E_F \cdot O ur quantum w ire is de ned as a$ system consisting of a nite scattering region that is connected left and right to sem i-in nite leads. The latter are supposed to be 'ideal' wires, which can be described by a periodic potential along the wire direction. In the scattering region the potential can have any shape. We consider two cases that can be treated by essentially the same technique. In the rst case the system has a nite cross-section perpendicular to the wire direction, whereas in the second case the system is periodic perpendicular to the wire. The latter case also covers planar interfaces and tunnel junctions.

In order to solve the scattering problem we generalize a m ethod form ulated by Ando.²⁸ Here one basically solves a single particle Schrodinger equation directly at a xed energy E in two steps. In the rst step one obtains the m odes of the ideal leads. Subsequently the wave functions for the scattering region are constructed such, that they are properly m atched to the solutions in the leads. W e use a real space nite di erence m ethod to represent the Schrodinger equation. In the following three subsections we will introduce this representation and discuss the steps required to solve the scattering problem.

A. Finite di erence approximation

W e start from a single particle equation of the general form

E V (r) +
$$\frac{2}{2m}$$
 r² (r) = 0; (2)

which represents the Schrödinger equation of a single particle in a potential V. Alternatively, within the DFT scheme it represents the Kohn-Sham equation with V the total e ective potential. We put the wave function

and the potentialV on a equidistant grid in real space $r = (x_j; y_k; z_l)$, where $x_j = x_0 + jh_x; y_k = y_0 + kh_y; z_l = z_0 + lh_z$ and $h_x; h_y; h_z$ are the grid spacings in x; y and z directions, respectively. Follow ing Refs. 25,26 we replace the kinetic energy operator in Eq. (2) by a high order

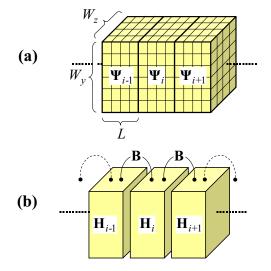


FIG.1: (Color online) (a) The system is divided into cells indicated by an index i. The cells have L W_y W_z grid points in the x;y and z directions, respectively. i is the supervector that contains the wave function values on all grid points in cell i. (b) H_i is the H am ilton matrix connecting grid points within cell i; the B -matrix connects grid points between neighboring cells and is independent of i.

FDA.For the x part this gives

$$\frac{\varrho^{2} (x_{j}; y_{k}; z_{1})}{\varrho x^{2}} = \frac{1}{h_{x}^{2}} \sum_{n=N}^{X^{N}} C_{n} (x_{j+n}; y_{k}; z_{1}); \quad (3)$$

with similar expressions for the y and z parts. Expressions for the coe cients c_n for various values of N are tabulated in Ref. 26. The simplest approximation in Eq.(3) (N = 1, where $c_1 = c_1 = 1$ and $c_0 = 2$) reduces Eq.(2) to the well-known simple nite di erence representation of the Schrodinger equation 12,21,22,23,24 How – ever, we will demonstrate that the scattering problem can be solved much more e ciently using higher order FDA's with N = 4-6.

In a FDA the Schrödinger equation of Eq. (2) becomes

(E
$$V_{j;k;l}$$
) $_{j;k;l}$ + $t_n^{X} t_{n-j+n;k;l} + t_n^{Y} t_{j;k+n;l} + t_{n-j;k+n;l} + t_{n-N}^{Z} t_{n-j;k;l+n-j;l}$

where V; $_{j;k;1}$ is a short-hand notation for V; $(x_{j};y_k;z_1)$ and $t_n^{x;y;z} = \sim^2 = 2m h_{x;y;z}^2$ g_n . In order to make a connection to Ando's form alism ²⁸ we divide the wire into cells of dimension a_x a_y a_z . The direction of the wire is given by the x-axis. The number of grid points in a cell is $L = a_x = h_x$, $W_y = a_y = h_y$, $W_z = a_z = h_z$ for the x, y and z directions respectively. We wish to distinguish between two di erent cases. In the rst case the wire has a nite cross-section in the yz plane. In the second case the wire has an in nite cross-section, but it has a periodic potential in the yz plane, i.e. $V_{j;k+W_y;1} = V_{j;k;1+W_z} = V_{j;k;1}$. In both cases the (unit) cell in the yz plane is described by W $_{\rm y}$ $\,$ W $_{\rm z}$ grid points.

The values $_{j;k;1}$ where the indices j;k;1 correspond to a single celliare grouped into a supervector $_i$. The idea is shown in Fig. 1. This supervector has the dimension N_{rs} = L W W, which is the total number of real space grid points in a cell. If we let i denote the position of the cell along the wire then Eq. (4) can then be rew ritten as

$$(E I H_i)_i + B_{i1} + B^{Y}_{i+1} = 0; (5)$$

for i = 1;:::;1. Here I is the N_{rs} N_{rs} identity matrix. The matrix elements of the N_{rs} N_{rs} matrices H_i and B can be derived straightforwardly from Eq. (4). The expressions are given in appendix A 1, both for a wire that is nite and for a wire that is periodic in the yz plane. For the latter $H_i = H_i(k_k)$, where k_k is a wave vector in the two-dimensional Brillouin zone. In the following this notation is suppressed.

Eq. (5) has the form of a nearest neighbor tight-binding equation, expressed in terms of vectors/m atrices of dimension N_{rs}. This form enables us to use Ando's technique to solve the scattering problem 28 Note however that the matrices B;B^y in Eq. (4) are singular, see Eq. (A3), which requires a generalization of this technique.

B. Idealwire

An ideal wire is de ned by a potential that is periodic in the direction of the wire, i.e. $V(x_j + a_x; y_k; z_l) =$ $V(x_j; y_k; z_l)$ or $V_{j+L;k;l} = V_{j;k;l}$. Since the potential is the same in each cell, the matrix $H_i = H$ in Eq. (5) is independent of the cell position i. In a periodic system the vectors in subsequent cells are related by the B loch condition

$$i = i + 1;$$
 (6)

where $= e^{ik_x a_x}$ with k_x real for propagating waves and complex for evanescent (growing or decaying) waves. C om bining Eqs. (5) and (6) one then obtains the following generalized eigenvalue problem

Form ally, the dimension of this problem is $2N_{rs}$. There are a number of trivial solutions, how ever, since B; B^Y are singularm atrices. In appendix A 2 it is shown how reduce the problem to its $2N_{W}$ W non-trivial solutions.

The non-trivial solutions of Eq. (7) can be divided into two classes. The rst class comprises B loch waves propagating to the right and evanescent waves decaying to the right; the corresponding eigenvalues are denoted by

(+). The second class comprises B loch waves propagating to the left or evanescent waves decaying to the left; the eigenvalues are denoted by (). The eigenvalues of the propagating waves have j ()j= 1 and for evanescent waves j ()j7 1. The evanescent states come in pairs, since it is easy to show that for every solution (+) there is a corresponding solution () = 1= (+). It can be shown that the propagating states also come in pairs, i.e. for every right propagating wave (+) there is a left propagating wave ().

It makes sense to keep only those evanescent waves for which $1 = \langle j j \langle , where$ is a su ciently large num – ber. States with j joutside this interval are extrem ely fast decaying or growing. Such states are not im portant in matching an ideal wire to a scattering region. Typical of nite di erence schemes there are also non-physical solutions to Eq. (7), which are related to so-called parasitic modes.^{33,34} These are easily recognized and discarded since their j js are either extrem ely sm all or large and thus falloutside the selected interval. M oreover, these j js are very sensitive to the grid spacing and rapidly go to 0 or 1 if the grid spacing is decreased.

A fter ltering out the physical and useful solutions Eq.(7) we end up with M pairs of solutions $_m$ ();m = 1;:::;M, where usually M $_{\rm rs}$. We construct the norm alized vectors u_m () from the rst $N_{\rm rs}$ elements of the eigenvectors of Eq.(7) and form the N $_{\rm rs}$ M m atrices

$$U() = (u_1()) M(u)$$
: (8)

Choosing the cell i = 0 as the origin, one then writes the general solution $_0$ in this cell as a linear combination of these right- and left going modes

$$_{0} = _{0}(+) + _{0}();$$
 (9)

where

$$X^{M}$$

 $_{0}$ () = U ()a() = u_{m} () a_{m} (); (10)
 $_{m=1}$

with a () vectors of arbitrary coe cients of dimension ${\rm M}$.

De ning the M M diagonal eigenvalue matrices by

$$(())_{nm} = _{nm} _{m} ();$$
 (11)

and using the B loch condition of Eq. (6), the solution in the other unit cells then can be expressed in a compact form

$$_{i} = U (+) ^{i} (+) a (+) + U () ^{i} () a ():$$
 (12)

In order to apply Ando's form alism ,²⁸ it is advantageous to slightly rewrite this. We de ne the N $_{\rm rs}$ $N_{\rm rs}$ m atrices F () and f^{2} () by

$$F()U() = U()();$$
 (13)

$$\mathbf{F}$$
 ()U() = U()¹(): (14)

Note that $\mathbf{\hat{F}}$ () $\mathbf{\hat{e}} \in \mathbf{F}^{1}$ () since the N_{rs} M matrices U () are not square (typically M N_{rs}). This presents

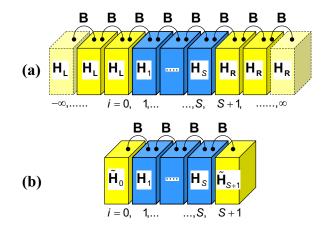


FIG.2: (Coloronline) (a) Schem atic representation of a quantum wire. The left (L) and right (R) leads are idealwires that span the cells i = 1;:::;0 and i = S + 1;:::;1, respectively. The scattering region spans cells i = 1;:::;S. (b) The reduced problem spans the cells i = 0;:::;S + 1, see Eq. (26).

no problem, how ever, and explicit expressions for the matrices \mathbf{f}^2 ; F are given in appendix A 3. They allow Eq. (12) to be rew ritten in recursive form

$$_{i+1} = F(+)_{i}(+) + F()_{i}();$$
 (15)

$$i_{1} = \mathbf{F}(+) i_{1}(+) + \mathbf{F}(-) i_{1}(-);$$
 (16)

either of which allows one to construct the full solution for the ideal wire, once the boundary values are set, cf. Eq. (9).

C. Scattering problem

In a non-ideal quantum wire the potential is not periodic, which means that we have to solve the Schrodinger equation of Eq. (5) with H $_{\rm i}$ depending upon the position i along the wire. The non-ideal region (the scattering region) is supposed to be nite, spanning the cells i = 1;:::;S.³⁵ The left and right leads are ideal wires, spanning the cells i = 1; :::;0 and i = S + 1; :::;1, respectively. In the ideal wires H i does not depend on the position of the cell. However, the left lead can be di erent from the right one, so we use the subscript L (R) to denote the form er(latter), i.e. $H_i = H_L$; i < 1 and $H_i = H_R$; i > S.A schem atic picture of the structure is shown in Fig. 2 (a). We solve Eq. (5) over the whole space, i = 1 ;1 , making use of the ideal wire solutions of the previous section to reduce the problem to essentially the scattering region only, see Fig. 2 (b).

For the solution in the left lead the recursion relation of Eq. (16) can be used. This gives for the cell i = 1

using Eq. (9). The vector $_0$ (+) describes a wave coming in from the left. In a scattering problem this vector xes the boundary condition. Eq. (17) allow SEq. (5) for i = 0to be written as

$$(E I \mathbb{P}_{0})_{0} + B^{Y}_{1} = Q_{0}(+); \quad (18)$$

where

$$\mathbf{P}_{0} = \mathbf{H}_{\mathrm{L}} \quad \mathbf{B}\mathbf{P}_{\mathrm{L}} ()$$

$$\mathbf{Q} = \mathbf{B} \left[\mathbf{P}_{\mathrm{L}} () \quad \mathbf{P}_{\mathrm{L}} (+)\right]:$$
(19)

For the solution in the right lead we use the recursion relation of Eq. (15), which gives for the cell i = S + 2

$$_{S+2} = F_R (+) _{S+1} (+)$$
: (20)

Here we have assumed that in the right lead we have only a right going wave, which corresponds to the transm itted wave. Eq. (20) allow s Eq. (5) for i = S + 1 to be written as

(E I
$$\Re_{S+1}$$
) $_{S+1}$ + B $_{S}$ = 0; (21)

where

$$\mathbf{f}_{S+1}^{P} = \mathbf{H}_{R} \quad \mathbf{B}^{Y} \mathbf{F}_{R} (+):$$
 (22)

Eqs. (19) and (22) take care of the coupling of the scattering region to the left and right leads. Eq. (5) for $i = 1; \ldots; S$ plus Eqs. (18) and (21) form a complete set of equations from which the vectors $_i; i = 0; \ldots; S + 1$ can be determined describing the waves in the scattering region.

The scattering rejection and transmission coecients can be deduced from the amplitudes immediately left and right of the scattering region, i.e. $_0$ and $_{S+1}$. If we let the incoming wave consist of one speci cmode, $_0$ (+) = $u_{L;n}$, i.e. a_m (+) = $_{m,n}$ in Eq. (9), then the generalized rejection and transmission probability amplitudes $r_n \circ_n$ and $t_n \circ_n$ are dened by

$$_{0}() = \underbrace{\overset{X}{\overset{L}}{\overset{L}}{\overset{L}{\underset{n^{0}=1}{}}} u_{L,n^{0}}()_{n^{0}n} \\ \overset{n^{0}=1}{\overset{X}{\overset{R}{\underset{n^{0}=1}{}}} u_{R,n^{0}}(+)_{n^{0}n}:$$
 (23)

Note that at this stage we include all evanescent and propagating modes since these form a complete set to represent the states in the leads. We assume the lead states to be amplitude norm alized.

The rejection and transm ission probability amplitudes $r_n \circ_n$ and $t_n \circ_n$ between all possible modes form a M_L M_L matrix R and a M_R M_L matrix T, respectively. All elements of these matrices can be found in one go by de ning a N_{rs} M_L matrix of all possible incoming modes, i.e.

$$C_0(+) = U_L(+)$$
: (24)

Analogous to Eq. (23) one then has

$$C_0() = C_0 C_0(+) = U_L()R$$

 $C_{S+1}(+) = C_{S+1} = U_R(+)T:$ (25)

Eqs. (18), (5) and (21) then become

0

i = 1; :::; S. Solving this set of equations for C_i; i = 0; :::; S + 1 gives all possible waves. From Eq. (25) one can then extract the generalized re ection and transm ission m atrices R and T. An e cient technique for solving the equations is discussed in appendix A 4.

In order to calculate the total transm ission one has to select the transm ission matrix elements that refer to propagating modes and discard the ones that refer to evanescent modes. This is easy, since the propagating modes have j j = 1, see the discussion above Eq. (8). The total transm ission of Eq. (1) is then given by

$$T(E) = \prod_{n=1,n^{0}=1}^{m X^{m_{R}}} \frac{V_{R,n^{0}}}{V_{L,n}} j_{n^{0}n} j_{j}^{2}; \qquad (27)$$

where $v_{\rm R\,,n^{\,0}}$ and $v_{\rm L\,,n}$ are the velocities in the x-direction of the right propagating waves in the right and left lead in the modes n^0 and n, respectively, and m $_{\rm L}$;m $_{\rm R}$ are the number of such modes. Introducing the velocities results from ux normalizing the modes, which is required by current conservation.¹² The velocities are given by the expression

$$v_n = \frac{2a_x}{\sim} \operatorname{Im} \quad {}_n u_n^{y} B^{y} u_n ; \qquad (28)$$

where subscripts L (R) need to be added for the left (right) leads. Eq. (28) is derived in appendix A 5. The sign of the calculated velocities is used to distinguish right from left propagating modes.

D. Computational costs

O ur computational method can be summarized as follows. First, Eq. (7) is solved in its reduced form, Eq. (A8), to obtain the modes for both leads. The computing costs of this step scale as N_{id}^3 , where $N_{id} = max(2N; L = N)$ W W, see appendix A 2. These costs are small compared to the costs of solving the scattering problem. The next step involves the selection of the physically relevant modes u_m and separate them into left (+) and right () going modes. The velocities are calculated using Eq. (28) and are used to distinguish left from right propagating states. Evanescent states are classi ed as growing (+) or decaying () on account of their eigenvalue. Subsequently, the F-m atrices are constructed, Eq. (13), and the matrix elements that de ne

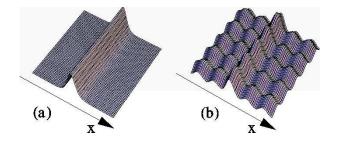


FIG.3: (Color online) The potential of Eq. (29) in the xy-plane for the cases (a) V_0 = 0 and (b) V_0 = V_1 .

the boundary conditions on the scattering region are set, see Eqs. (19) and (22). The computing costs of these steps are m inor.

The transmission matrix T is obtained by solving Eq. (26) using the algorithm of appendix A 4. This is the most time consuming step. It scales as S \dot{M}_{s} , where N_{rs} = L W W is the number of grid points in the unit cell and S is the number of unit cells in the scattering region. Note that the scaling is linear with respect to the size S of the scattering region, which means that this algorithm can be classified as O (N). Finally, the total transmission and the conductance can be obtained from Eqs. (27) and (1).

III. RESULTS

A. Num erical tests

In order to test the accuracy of our method we consider a system described by the model potential

$$V (r) = V_0 [\cos(2 x=a) + \cos(2 y=a) + \cos(2 z=a)] + \frac{V_1}{\cosh^2 (x=a)};$$
(29)

The V_0 term describes an ideal wire by a simple three dimensional periodic potential with periods $a_x = a_y =$ $a_z = a$. The V_1 term describes a barrier in the propagation direction and is a sim plem odel for a tunnel junction. The potential is plotted in Fig. 3. We solve the scattering problem for this system num erically in three dimensions by the method outlined in Sec. II. Our results can be veried, how ever, since this potential is in fact separable and lim iting cases can be solved analytically. The solutions in the y- and z-directions are M athieu functions. $^{\rm 36}$ If $V_1 = 0$ then the solutions in the x-direction are also M athieu functions. If $V_1 \in 0$ but $V_0 = 0$ the scattering problem can be solved analytically.³⁷ F inally, if $V_1 \notin 0$ and $V_0 \in 0$ the solution in the x direction can be obtained using the separability of the potential and a standard num erical solver for the resulting ordinary di erential equation in the x-direction.³⁸ In the following the latter will be called the \exact" num erical solution.

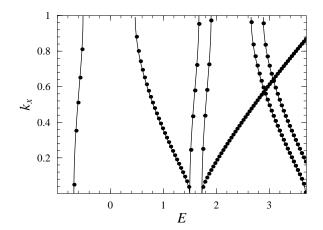


FIG. 4: The calculated wave number k_x (in units of =a) as function of the energy E (in units of V_0) for an ideal wire. The points indicate the num erical results obtained with L;W $_y$;W $_x$ = 8 and N = 4. The solid line indicates the exact solution of the M athieu problem .

As a rst test we consider an ideal wire, i.e. $V_1 = 0$ in Eq. (29). The potential is separable and we can write the energy as E $(k_x;k_y;k_z) = n_x (k_x) + n_y (k_y) + n_z (k_z)$, where $n(k); k = -a; \dots; a; n = 0; 1; \dots$ are the eigenvalues of the Mathieu problem .³⁶ Fig. 4 shows part of the analytical band structure for $(k_x;k_y;k_z) =$ (0;0;0) ! (=a;0;0). It essentially consists of a superposition of one-dimensional band structures $n_x (k_x) = o$ by energies $n_y (0) + n_z (0); n_y; n_z = 0; 1; \dots$

The numerical band structure is obtained by solving Eq. (7) in its reduced form, Eq. (A8). To obtain the results shown in Fig. 4 we set $k_k = (k_y; k_z) = (0; 0)$, cf. Eq. (A4), and determ ine the eigenvalues in Eq. (7) as a function of E. For the propagating states one can write $= \exp(ik_x a)$. P botting the calculated wave number k_x as function of the energy E then allows to compare the results with the analytical band structure. The numerical results shown in Fig. 4 are obtained using a grid of L;W_y;W_z = 8 points perpended and a FDA with N = 4. A lthough this grid is relatively coarse, we obtain a relative accuracy on k_x of 10³.

This perhaps supprising accuracy is entirely due to the use of a high order FDA. To illustrate this, Table I shows the convergence of k_x at a num berofenergies E as a function of the order N of the FDA and the number of grid points L. These particular results were obtained using the separability of the potential and solving the problem num erically in the x-direction only, while using analytical solutions for the y- and z-directions. For N = 6 and L = 14 the results are converged to within 10⁷ of the exact result. This is in sharp contrast to the results obtained with a simple rst order (N = 1) FDA, where a similar convergence can only be obtained at the cost of using two orders of magnitude m ore grid points. Using such a large number of grid points in three dimensions is entirely prohibitive because of the high computational

TABLE I: k_x (E) (in units of =a) at values of E (in units of V₀) in the lowest two bands and in the rst band gap of Fig. 4; in the band gap we nd $k_x = 1 + i_x$.

Ν	L	k _x (() : 6)	k _x (1:0)	x (0:3)
1	7	0.694	906	0,283091	0.283549
	10	0.608	958	0.322712	2 0.304238
	14	0.571	387	0.342011	0.312259
	100	0.533	341	0.35918	0.319658
	1000	0.533	084	0.359425	5 0.319688
4	5	0.544	347	0.355049	0.317777
	7	0.533	962	0.35892	0.319476
	10	0.533	149	0.359389	0.319673
	14	0.533	087	0.359425	5 0.319687
6	7	0.533	228	0.35933	7 0.319658
	10	0.533	086	0.359425	5 0.319688
	14	0.533	082	0.359428	3 0.319688
Exact		0.533	082	0.359428	3 0.319688

costs involved. For example, aim ing at a moderate accuracy of 10 2 , it is observed that for N = 4 and L = 5 the results are markedly better than for N = 1 and L = 14. Yet in a three dimensional calculation, without using the separability of the potential, the computing time required for the latter is two orders of magnitude larger than for the form er. It means that in order to solve a general non-separable three dimensional costs, it is vital to use a high order FDA.

Next we consider the scattering problem and calculate the total transm ission for the case where V₁ 6 0. The size of the scattering region is set to Sa and outside this region the scattering potential (the last term of Eq. (29)) is set to zero. W ith S = 6 the results are extremely well converged. As an example we have calculated the transmission at norm al incidence, i.e. $k_k = (k_y; k_z) = (0; 0)$. The crosses marked V₀ = 0 in Fig. 5 represent the numerical results for the transmission of the corresponding potential, obtained with a L;W_y;W_z = 8 grid and a N = 4 FDA. This scattering problem can also be solved analytically,³⁷ and the analytical and numerical transmission probabilities agree within 10⁴.

Fig. 5 also shows the transm ission for the case where $V_0 = V_1$ as calculated num erically using the same param – eters as before, i.e. $S = 6; L; W_y; W_z = 8; N = 4$. This scattering problem can only be solved sem i-analytically; M athieu solutions are used in y- and z-directions, and the (ordinary) di erential equation for the x-direction is solved \exactly" using an accurate standard num erical solver.³⁸ A gain the \exact" and num erical transm ission probabilities agree within 10⁴. C om pared to the $V_0 = 0$ case it is observed that the in uence of the periodic potential of the leads upon the transm ission is large. For $V_0 = V_1$ the electronic states in the leads are far from free electron-like, see Fig. 4. In particular, the transm ission

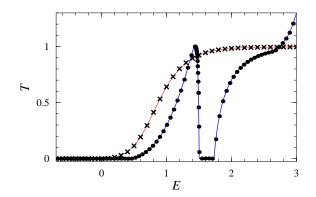


FIG. 5: (Color online) The total transmission as function of energy (in units of V_1) for the two cases $V_0 = 0$ (crosses) and $V_0 = V_1$ (dots). In both cases $k_k = (0;0)$. The solid lines represent the analytical solution for $V_0 = 0$ and the \exact" numerical solution for $V_0 = V_1$.

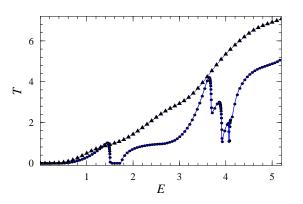


FIG. 6: (Color online) The total transm ission as function of energy (in units of V_1) for the two cases $k_k = (0;0)$ (dots) and $k_k = (0:47;0:21) = a$ (triangles). In both cases $V_0 = V_1$. The solid lines represent the \exact" num erical solution.

drops to zero if the energy is inside a band gap, because there are no lead states of that energy.

The numerical calculations accurately capture the transm ission curve over a large energy range, as is shown in Fig. 6. The transm ission generally increases with energy due to the increasing number of channels, see Fig. 4. Since the density of states peaks at the band edges, the transm ission peaks at the corresponding energies. The transm ission depends very much upon k_k as can be observed in Fig. 6, where the transm ission for normal incidence, $k_k = (0;0)$, can be compared to that for $k_k = (0:47;0.21) = a$ (an arbitrary point in the Brillouin zone). The difference between the two curves can be easily understood from the band structure of the leads. In particular, for $k_k = (0:47;0.21) = a$ there are no band gaps for $E > 0:14V_0$.

To dem onstrate the convergence of the num erical calculations, Fig.7 shows the total transm ission as function of the sampling density $L = W_y = W_z$ for a simple N = 1

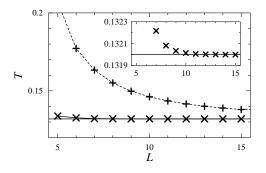


FIG.7: The total transm ission T as function of the grid size $L = W_y = W_z$ for a simple N = 1 FDA, +' top curve, and for a N = 4 FDA, ' bottom curve. The horizontal line represents the \exact" value T = 0:132. The inset shows the N = 4 curve on a ner scale for T.

and a high order N = 4 FDA. The results shown are for one particular $k_k = (k_v; k_z) = (0.47; 0.21)$ = a and energy $E = 0.895 V_0$, but the convergence at other k_k -points and energies is very sim ilar. The number of propagating channels at this k_k -point and energy is two, but the total transmission is only T = 0.132, which means that the barrier is largely re ecting. We conclude that the accuracy of the three-dimensional calculation depends very strongly upon the order of the FDA. For N = 1; L = 15, the transm ission is converged on a scale of 10 2 only, but for N = 4 it is converged on a scale of 10³ already for L = 8, see the inset of Fig. 7. A high order FDA thus enables the use of a much coarser real space grid. Since the com putational costs scale with the num ber of real space grid points N $_{rs} = L^3 as N _{rs}^3 = L^9$, this dem onstrates the strength of using a high order FDA.

B. Sodium atom ic wires

W e have calculated the electronic transport in sodium atom ic w ires as examples of m ore complex system s. O ur model of a sodium wire consists of left and right leads composed of bulk (bcc) sodium metal term inated by a (100) surface, connected by a straight wire of sodium atom s, as is shown in Fig. 8. The atom s in the leads are positioned according to the bcc structure of bulk sodium, with the cellparam eter xed at the experim entalvalue of 7.984 a_0 .³⁹ The atom s in the wire are xed at their (bulk) nearest neighbor distance of $6.915 a_0$. Since geometry relaxation at the Na(100) surface is very small, 40 and calculations using jellium electrodes have shown that the conductance of a sodium wire is not very sensitive to its geometry,⁴¹ we have refrained from optimizing the geometry. Perpendicular to the wire we apply periodic boundary conditions using a 2 2 lateral supercell, which has a lattice parameter of $15.968 a_0$.

If DFT is used to model the electronic structure, Eq. (2) corresponds to the Kohn-Sham equation. The one-

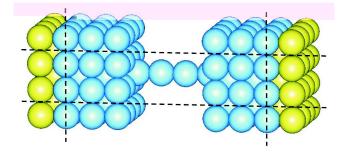
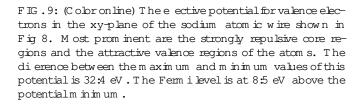


FIG.8: (Color online) Structure of an atom ic wire consisting of 4 sodium atom s between two sodium leads term inated by (100) surfaces. The scattering region is bounded by the vertical lines and the lateral supercell by the horizontal lines. Bulk atom s are indicated by yellow (light grey) balls and atom s in the scattering region by blue (dark grey) balls, respectively.

electron potential V (r) in this equation is then given by the sum of the nuclear Coulom b potentials or pseudopotentials, and the electronic Hartree and exchangecorrelation potentials. The latter two depend upon the electronic charge density. In linear response the charge density remains that of the ground state, allowing the electronic potentials to be obtained from a self-consistent ground state calculation. In these calculations we employ supercells containing a slab of 13 layers to represent the bulk and surface of the leads, and a wire of n atom s, see Fig. 8. We use the local density approximation, 42 and represent the ion cores of the sodium atom s by a local pseudopotential.43 The valence electronic wave functions are expanded in a plane wave basis set with a kinetic energy cuto of 16 Ry. The lateral Brillou in zone is sam pled with a 8 8 k-point grid, using a tem perature broadening with $kT_{el} = 0:1 \text{ eV}$.

We want to calculate the conductance for various lengths of the atom ic wire, so for each length n we perform a self-consistent supercell calculation to generate the one-electron potential. By expressing the latter in a plane wave basis, Fourier interpolation can be used to obtain a representation on any real space grid required for the transport calculations, cf. Eq. (4). An example of the electron potential for valence electrons of a sodium atom ic wire is shown in Fig. 9.

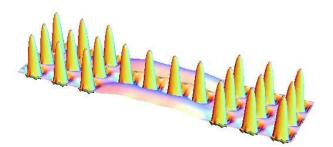
For the transport calculations we use a scattering region comprising the atom ic wire and the surface regions of the left and right leads. B oth surface regions consist of 5 atom ic layers, see F ig. 8. Periodic boundary conditions and a 2 2 lateral supercell perpendicular to the wire are applied. The potential in the scattering region is extracted from the slab calculations. O utside the scattering region we assume that the leads consist of bulk sodium. The potential for the leads and the value of the Ferm i energy are extracted from a bulk calculation. The average bulk potential is lined up with the average potential in the middle of the supercell slab.⁴⁵ W e have checked that the spatial dependence of the bulk potential is virtually identical to that of the potential in the middle of



the slab. This means that the connection between the leads and the scattering region is smooth. There are no discontinuities in the potential in the boundary regions that could cause spurious re ections.

Fig.10 shows the calculated conductance G (E $_{\rm F}$) at the Ferm i level as a function of the length n of the sodium atom ic wire. The conductance is calculated using a grid spacing along x; y and z directions of $h_{x;y;z} = 0.67 a_0$ (giving L = $6;W_y = W_z = 24$) and a FDA of order N = 4.46 The 2 2 lateral B rillouin zone is sampled by 12 uniform k_k-point grid. With these paramea 12 ters the calculated conductances have converged to well. within 10³ G₀ (where $G_0 = e^2 = (\sim)$).⁴⁷ Allwires have a conductance close to unity, except the one-atom (n = 1)wire. The high conductance for the one-atom wire is foremost due to tunneling between the left and right leads through vacuum . The latter can be calculated by om itting the wire and otherwise keeping the geometry xed. Tunneling through vacuum leads to a conductance of 220 G₀ per 2 2 surface cell. Vacuum tunneling decreases fast with the distance between left and right lead surfaces. At a distance corresponding to the two-atom wire it gives a conductance of $0.047 \, \text{G}_0$; at distances corresponding to longer wires this conductance is negligible. Subtracting these vacuum tunneling values gives the lower curve in Fig.10.

W ith the exception of the one-atom ic w ire, the conductances are close to unity. This is perhaps not surprising, since w ithin a tight-binding m odel atom ic w ires consisting of a monovalent atom like sodium are expected to have one open channel. For perfectly transm itting contacts this would give a conductance of 1 G $_0$.⁴⁸ O ur calculated conductances for n > 1 are less than 15% sm aller than this value, demonstrating that this transm ission is indeed very high. The conductance of the one-atom ic w ire, relative to the vacuum tunneling conductance at this distance, is signi cantly low er than unity. The electronic structure of a single atom betw een two electrodes is substantially distorted from the sin ple single open chan-



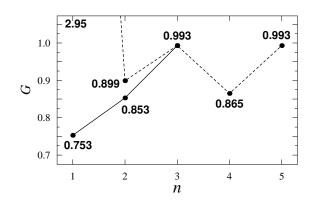


FIG.10: Top curve: conductance G (E $_{\rm F}$) at the Ferm i level (in units of e² = ~) of a sodium atom ic wire as a function of the number of atom s n in the wire. Bottom curve: conductance of a sodium atom ic wire relative to vacuum tunneling conductance between two electrodes without wire.

nelmodel.8

On a ner scale we nd evidence of an even-odd oscillation in the conductance obtained in previous studies.^{8,49,50,51,52} The conductance for wires with n even tends to be lower than for those with n odd. In simple tight-binding term s odd-num bered atom ic wires have a non-bonding level that tends to line up with the Ferm i level of the leads, which gives a high transm ission. For an even-num bered atom ic wire on the other hand the Ferm i level tends to fall in the gap between the bonding and anti-bonding levels of the wire, resulting in a lower transm ission.⁵³ The size of the even-odd oscillation in the conductance depends of course upon the nature of the contacts between the atom ic wire and the leads. Good contacts broaden the levels of the atom ic wire into wide resonances, which tends to suppress the even-odd oscillation. Our wires have good contacts, but the even-odd oscillation remains distinctly visible.54

IV. SUMMARY

W e have form ulated and im plem ented a new num erical technique for calculating electronic transport in quantum wires and tunnel junctions in the linear response regime, starting from Landauer's scattering form alism. It is based upon a real space grid representation of the scattering problem . Dividing space into left and right ideal leads and a scattering region, the problem is solved by wave function matching (W FM). First all propagating and evanescent B loch m odes of the leads are calculated. Subsequently the states in the scattering region are forced to match to the Bloch modes of the leads. This directly leads to the transm ission matrix, which contains the transm ission probability am plitudes between all m odes of the left and right leads, and to the conductance. The computing costs of this algorithm scale linearly with the size of the scattering region.

It is shown that the use of a high order nite difference approximation for the kinetic energy operator leads to a high accuracy and e ciency. This is demonstrated for a model potential by benchmarking the technique against analytical and numerically \exact" solutions. The method is then applied to calculate the conductance in sodium atom ic wires, where the potential in the wire and in the bulk sodium leads is obtained from self-consistent DFT calculations.

A cknow ledgm ents

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APPENDIX A: COMPUTATIONAL DETAILS

1. H and B m atrices

In this section the matrices H $_{\rm i}$ and B, introduced in Sec. IIA, are presented explicitly. In order not to com plicate the notation the subscript i is dropped; all quantities refer to a single cell. For a wire with a nite cross-section in the yz plane, the matrix H is real and symmetric and has the form

0								-	L
	h_1	1	:::			:::		0	~
В П П П П	1		:::	N 1				0	X X
$H = B_{B}$	÷	÷	÷	:	÷	÷	÷	:	× × :
e B	0	0	:::		0	::: l	l _{L 1}	1	Ă
	0	0	:::	0	0		1		
								(A	1)

Here N is the order of the nite di erence form ula used, see Eq. (3). W e assume that the x-axis is in the direction of the wire. L is the number of grid points in the xdirection of the unit cellde ned by the periodic potential.

The submatrices h_n and $_n$ are ofdimension $W_y = W_z$, which is the number of grid points in the cross section of the wire. Denoting $(k; l) = k + (l = 1)W_y; k =$ $l; :::; W_y; l = 1; :::; W_z$ as the compound index covering the grid points in the cross section, the non-zero elements of these matrices are easily derived from Eq. (4).

where N n; n N and 1 k; k + n W; 1 l; l + n⁰ W_z; 1 j N. Note that in writing down these matrices we have assumed that N < L; W_y; W_z. In practical calculations on realistic systems this will always be the case.

The matrix B has the same dimension as H , but it is upper triangular

$$B = \begin{bmatrix} 0 & & & & & 1 \\ 0 & ::: & 0 & N & N & 1 & ::: & 1 \\ 0 & ::: & 0 & 0 & N & ::: & 2 \\ 0 & :: & 0 & 0 & N & ::: & 2 \\ 0 & :: & 0 & 0 & 0 & ::: & N \\ 0 & :: & 0 & 0 & 0 & ::: & N \\ 0 & :: & 0 & 0 & 0 & ::: & 0 \end{bmatrix}$$
(A 3)

For a wire that is periodic in the yz plane, the wave functions in Eq. (4) must obey B loch conditions. That is, $_{j;k+W_{y};l} = e^{ik_{y}a_{y}} _{j;k;l}$ and $_{j;k;l+W_{z}} = e^{ik_{z}a_{z}} _{j;k;l}$, where $a_{y};a_{z}$ are the periods in the y and z directions, and $(k_{y};k_{z}) = k_{k}$ is the B loch wave vector in the yz plane. These B loch conditions in the yz plane can be taken into account by de ning the blocks

The matrix H (k_k) , which is obtained by substituting h_j by $h_j + h_j^0$; j = 1; :::; L in Eq. (A 1) describes a wire that is periodic in the yz plane with solutions corresponding to a B loch vector k_k . This matrix is (com plex) Herm itian.

2. Idealwire

For an ideal w ire, which has a periodic potential along the w ire, Eq. (7) has to be solved to nd the propagating and the evanescent waves. The precise form of the submatrices in Eqs. (A1) and (A3) is not important in the following discussion. For ease of notation we only mention the dimensions L (the number of grid points in the x-direction) and N (the order of the nite di erence expression) explicitly and treat the wire as quasi onedimensional. To nd the dimensions of the matrices in the three-dimensional case, one simply has to multiply the dimensions mentioned below by W_x W_z .

Eq. (7) is a generalized eigenvalue problem of dimension 2L. Because the matrix B is singular it has a number of trivial solutions = 0 and = 1. By using a partitioning technique we will eliminate these trivial solutions and reduce the problem to the 2N non-trivial solutions. The key point is to split the vectors $_i$ into two parts containing the rst L N and last N elements, respectively. The two parts are denoted by the subscripts 1 and

2. Splitting the matrices ${\rm H}$ and ${\rm B}$ in the same way one gets

Note the special form of the matrix ${\ensuremath{\mathsf{B}}}$.

This splitting allow s Eq. (7) to be written in the form
0
$$1$$

E I₁₁ H₁₁ H₁₂ 0 B₁₂
B H₂₁ + B^y₂₁ E I₂₂ H₂₂ + B^y₂₂ 0 B₂₂ E
0 I₁₁ 0 I₁₂ 0 I₂₂
0 I₂₂ 0 I₂₂
0 I₂₂ 0 I₂₂
B $\frac{i_{j1}}{i_{j2}} \sum_{A}^{C} = 0;$ (A 6)
i 1;2

From this expression it is clear that the component $i_{1;1}$ only enters the problem in a trivial way as $i_{1;1} = 1 = i_{1;1}$. It can be eliminated by deleting the third row and column in Eq. (A 6).

Furtherm one the rst row of the matrix does not depend upon the eigenvalue . W riting out the multiplication for the rst row explicitly, one nds an expression for $_{\rm i;1}$

$$_{i;1} = (E I_{11} H_{11})^{1} (H_{12} i;2 B_{12} i;1;2): (A7)$$

This can be used to eliminate $_{i;1}$ from Eq. (A6) to arrive at the equation

w ith

...

$$A_{11} = E I_{22} \qquad H_{22} \qquad H_{21} (E I_{11} \qquad H_{11})^{1} H_{12}$$

$$A_{12} = H_{21} (E I_{11} \qquad H_{11})^{1} B_{12}$$

$$S_{11} = B_{22}^{Y} \qquad B_{21}^{Y} (E I_{11} \qquad H_{11})^{1} H_{12}$$

$$S_{12} = B_{21}^{Y} (E I_{11} \qquad H_{11})^{1} B_{12} : (A 9)$$

Eq. (A8) is a generalized eigenvalue problem of dimension 2N that can be solved using standard numerical techniques.⁵⁵ In general it gives 2N eigenvalues m and eigenvectors u_m . As mentioned in the text, some of these solutions are non-physical,^{33,34} others represent extrem ely fast growing or decaying waves. Both of these classes of unwanted solutions are easily litered out by dem anding that 1 = < j j <, where is some threshold value. We use this criterion to select the physically relevant solutions, which are then separated into M right-going and M left-going solutions. These are used to construct the matrices of Eqs. (8) and (11) which contain all the inform ation required to describe the ideal wire.

The computational cost of solving Eq. (A8) scales as $(2N)^3$, whereas the cost of computing the matrices of Eq. (A9) basically scales as $(L N)^3$ (which is the cost of thematrix inversion involved). D epending on the relative sizes of L and N one of these two steps is dominant.

3. F m atrices

In this section explicit expression for the matrices F and $\mathbf{\hat{F}}$ are given, see Eqs. (13) and (14). Following Eq. (8), we denote the propagating and evanescentm odes of the ideal wire by u_m ; $m = 1; \dots; M$, where $M < N_{rs}$ and N_{rs} is the dimension of the vectors. For clarity of notation we om it the labels for right- and left-going modes here. As in Eq. (8) we form the N_{rs} M matrix

$$U = (u_1 M) u (A10)$$

$$= \overset{\text{U}_{11}}{\textcircled{e}} : : \overset{\text{U}_{1M}}{\vdots} \overset{\text{C}}{A} : (A 11)$$

$$u_{N_{rs}1} ::: u_{N_{rs}M}$$

The mode vectors u_m are in general non-orthogonal and we can form the M M (positive de nite) overlap matrix with elements

$$S_{mn} = u_m^y u_n$$
 hum jun i: (A 12)

This allows us to construct the dual basis \mathfrak{e}_m ;m = 1;:::;M

$$\mathbf{e}_{m} = \sum_{n=1}^{X^{M}} S_{m n}^{1} u_{n};$$
 (A13)

with properties

$$he_m ju_n i = hu_m je_n i = m_n$$
: (A14)

Now de ne the M N_{rs} matrix

$$\mathfrak{F} = (\mathbf{e}_{1} \quad \mathbf{e}_{M})^{\mathrm{Y}}$$

$$\mathfrak{e}_{11} \quad ::: \quad \mathfrak{e}_{N_{rs}1}$$

$$\mathfrak{e}_{1} \quad ::: \quad \mathfrak{e}_{N_{rs}M}$$

$$\mathfrak{e}_{1M} \quad ::: \quad \mathfrak{e}_{N_{rs}M}$$

$$\mathfrak{e}_{1M} \quad ::: \quad \mathfrak{e}_{N_{rs}M}$$

 ${\rm F}$ is called the pseudo-inverse of U ; note that ${\rm F}$ U = ${\rm I}_M$, where ${\rm I}_M$ is the M $\,$ M identity matrix 55

De ning the matrix

$$F = U \mathfrak{F};$$
 (A16)

It is easy to show that it is a solution to Eq. (13). F is in fact a m atrix that projects onto the space spanned by the m odes, as is easily dem onstrated by writing Eq. (A16) as

$$\mathbf{F} = \int_{m=1}^{X^{1}} \mathbf{j}_{m} \mathbf{i}_{m} \mathbf{h} \mathbf{e}_{m} \mathbf{j} \qquad (A \, 17)$$

making use of Eqs. (11) and (A 10)-(A 15). In a similar way a solution to Eq. (14) is formed by

Note that $\hat{\mathbf{F}} = F^{-1}$ only if $M = N_{rs}$, but since MN $W_x W_y < N_{rs}$ (see the previous section) this will never be the case.

4. Scattering problem

The scattering problem is described by Eq. (26). It is conveniently written in matrix form as

0						1 0		1	0		1
	Α ₀	ВУ	0	:::	0		C 0			D	
BBR	В	A $_1$	ВУ	:::	0	CBB	C 1	ç	BBB	0	CC
B	0	В	Α2	:::	0	ζ₿	C 2	ğ	= B	0	Č(A; 19)
DB B B B B B B B B B B B B B B B B B B	÷	:	÷	÷	÷	C B A C	C 1 C 2 :	Č A	DB@	÷	C A
	0	0	0	:::	A _{S+1}		C _{S+1}			0	

w ith

$$A_{0} = EI \quad ff_{0}$$

$$A_{i} = EI \quad H_{i}; i = 1; :::; S$$

$$A_{S+1} = EI \quad ff_{S+1}$$

$$C_{0} = U_{L}(+) + U_{L}()R$$

$$C_{S+1} = U_{R}(+)T$$

$$D = QU_{L}(+): \quad (A20)$$

All the blocks A -D are N $_{\rm rs}$ N $_{\rm rs}$ matrices. Eq. (A 19) represents a set of linear equations, which can be solved directly using a standard algorithm . However, the dimension of this problem is N $_{\rm tot}$ = N $_{\rm rs}$ (S + 2), which can be rather large. Since the computing cost scales as N $_{\rm tot}^3$ the direct route is not very practical.

It is how ever quite straightforward to construct an algorithm for which the computing cost scales as N_{rs}^3 S, i.e. only linearly with the size S of the scattering region. One has to make optimal use of the block tridiagonal form of the matrix in Eq. (A19). The algorithm is a block form of G aussian elimination. The rst (and most time consuming) step of this algorithm is transforming the matrix into upper block triangular form by iteration

$$A_{0}^{0} = A_{0}; D_{0}^{0} = D;$$

$$A_{i}^{0} = A_{i} BA_{i1}^{0} B^{y}$$

$$D_{i}^{0} = BA_{i1}^{0} D_{i1}^{0}$$

$$i = 1; ...; S + 1:(A 21)$$

The inverse matrices A $^{0\ 1}_{i\ 1}$ in this algorithm are actually not needed explicitly. Instead at each step one solves the sets of linear equations

$$A_{i1}^{0} B_{i}^{0} = B_{i1}^{y}; A_{i1}^{0} B_{i}^{0} = D_{i1}^{0};$$
 (A 22)

by a standard algorithm , i.e. LU decom position of A $^{0}_{i\ 1}$ followed by back substitution, to obtain the matrices $\hat{\mathbf{B}}_{i}$ and $\hat{\mathbf{IP}}_{i}$.⁵⁵ T his allow s the steps in Eq. (A 21) to be rew ritten as

$$A_{i}^{0} = A_{i} \quad BB_{i}; D_{i}^{0} = BB_{i}: \quad (A23)$$

The solution to Eq. (A19) can now be found by back substitution

$$C_{s+1} = A_{s+1}^{0} D_{s+1}^{0}$$

$$C_{i} = B_{i+1}^{0} B_{i+1}^{0} C_{i+1}^{0} i = S; ...; 0: (A 24)$$

Again one does not need A $^{0}_{S+1}$ explicitly, but like Eq. (A 22) one can solve the equivalent set of linear equations. The rejection and transmission matrices R and T can be extracted using the special form of the matrices C $_0$ and C $_{S+1}$, see Eq. (A 20).

Very often one is only interested in the transmission matrix. In that case one only uses the rst step of the back substitution, Eq. (A 24), which can be written as

$$A_{S+1}^{0}U_{R}$$
 (+)T = D_{S+1}^{0} : (A25)

T his is a set of linear equations for the transm ission probability am plitudes T , which can be solved using a standard num erical techniques. 55

The time consum ing steps consist of solving Eq. (A 22), the computing costs of which scale as $N_{rs}^{3,56}$ Using Eq. (A 23) in Eq. (A 21) requires perform ing S + 1 of such steps and subsequently solving Eq. (A 25) scales as N_{rs}^{3} . Note that the full algorithm scales linearly with the size S of the scattering region.

5. Velocities

In this section we give a short derivation of the expression for the velocities, Eq. (28). It is straightforward to show that the vectors u_m of Eq. (8) are a solution of the quadratic eigenvalue equation

$$_{m}$$
 (EI H) u_{m} + B u_{m} + $_{m}^{2}$ B $^{y}u_{m}$ = 0: (A26)

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W e now start from

$$_{m} u_{m}^{y}$$
 (E I H) $u_{m} + u_{m}^{y} B u_{m} + \frac{2}{m} u_{m}^{y} B^{y} u_{m} = 0;$ (A 27)

and take the derivative d=dE of this expression. All the term s with $du_m = dE$ and $du_m^{\gamma} = dE$ drop out, because u_m and u_m^{γ} obey Eq. (A 26) and its com plex conjugate, respectively. The remaining term s can be collected and slightly rewritten using Eq. (A 26); the result is

$$\frac{d_{m}}{dE} \int_{m}^{1} u_{m}^{y} B u_{m} \int_{m}^{m} u_{m}^{y} B^{y} u_{m} + \int_{m}^{m} u_{m}^{y} u_{m} = 2\frac{d_{m}}{dE} Im \int_{m}^{m} u_{m}^{y} B^{y} u_{m} + \int_{m}^{m} = 0; \quad (A28)$$

where the last line is obtained by making use of $m^1 = m$ and the fact that the vectors are normalized, $u_m^y u_m = 1$. Eq. (A 28) yields an expression for $d_m = dE$. For propagating states $m = e^{ik_x a_x}$ and thus

$$\frac{dk_x}{dE} = \frac{1}{ia_{x m}} \frac{d_m}{dE}$$
 (A 29)

The usual de nition of the Bloch velocity $v_n = \sim {}^1 dE = dk_x$ and the expression for d $_m = dE$ extracted from Eq. (A 28) then give the expression for the velocity of Eq. (28).

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